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Datasheet of TPS54286PWPR - IC REG BUCK ADJ 2A DL 14HTSSOP

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TPS54283, TPS54286

SLUS749C-JULY 2007-REVISED OCTOBER 2007

2-A DUAL NON-SYNCHRONOUS CONVERTER WITH INTEGRATED HIGH-SIDE MOSFET

FEATURES

•	4.5-V	to	28-V	Input	Range
---	-------	----	------	-------	-------

- Output Voltage Range 0.8 V to 90% of Input Voltage
- Output Current Up to 2 A
- Two Fixed Switching Frequency Versions:
 - TPS54283: 300 kHz
 - TPS54286: 600 kHz
- Two Selectable Levels of Overcurrent Protection (Output 2)
- 0.8-V 1.5% Voltage Reference
- 2.1-ms Internal Soft Start
- Dual PWM Outputs 180° Out-of-Phase
- Ratiometric or Sequential Startup Modes Selectable by a Single Pin
- 100-mΩ Internal High-Side MOSFETs
- Current Mode Control
- Internal Compensation (See Page 16)
- Pulse-by-Pulse Overcurrent Protection
- Thermal Shutdown Protection at 148°C
- 14-Pin PowerPAD™ HTSSOP package

APPLICATIONS

- Set Top Box
- Digital TV
- Power for DSP
- Consumer Electronics

CONTENTS

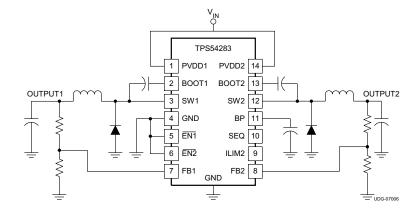
Device Ratings	2
Electrical Characteristics	3
Device Information	9
Application Information	12
Design Examples	32
Additional References	44

DESCRIPTION

TPS54283 and TPS54286 are dual output non-synchronous buck converters capable of supporting 2-A output applications that operate from a 4.5-V to 28-V input supply voltage, and require output voltages between 0.8 V and 90% of the input voltage.

With internally-determined operating frequency, soft start time, and control loop compensation, these converters provide many features with a minimum of external components. Channel 1 overcurrent protection is set at 3 A, while Channel 2 overcurrent protection level is selected by connecting a pin to ground, to BP, or left floating. The setting levels are used to allow for scaling of external components for applications not needing the full load capability of both outputs.

The outputs may be enabled independently, or may be configured to allow either ratiometric or sequential startup sequencing. Additionally, the two outputs may also be powered from different sources.



A

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TPS54283, TPS54286



SLUS749C-JULY 2007-REVISED OCTOBER 2007



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION(1)

PART NUMBER	OPERATING FREQUENCY (kHz)	PACKAGE	MEDIA	UNITS (Pieces)
TPS54283PWP	300		Tube	90
TPS54283PWPR	300	Plastic 14-Pin HTSSOP	Tape and Reel	2000
TPS54286PWP	600	Plastic 14-PIII HT330P	Tube	90
TPS54286PWPR	600		Tape and Reel	2000

For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

DEVICE RATINGS

ABSOLUTE MAXIMUM RATINGS(1)

		VALUE	UNIT
	PVDD1, PVDD2, EN1, EN2	30	
	BOOT1, BOOT2	V _{SW} + 7	
	SW1, SW2	-2 to 30	
Input voltage range	SW1, SW2 transient (< 50ns)	−3 to 31	V
	ВР	6.5	
	SEQ, ILIM2	-0.3 to 6.5	
	FB1, FB2	-0.3 to 3	
	SW1, SW2 output current	7	Α
	BP load current	35	mA
T _{stg}	Storage temperature	-55 to +165	
T _J	Operating temperature	-40 to +150	°C
	Soldering temperature	+260	

Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{PVDD2}	Input voltage	4.5	28	V
TJ	Operating junction temperature	-40	+125	°C

ELECTROSTATIC DISCHARGE (ESD) PROTECTION

	MIN	UNIT
Human body model	2k	
CDM	1.5k	V
Machine Model	250	

PACKAGE DISSIPATION RATINGS (1)(2)(3)

PACKAGE	THERMAL IMPEDANCE JUNTION-TO-THERMAL PAD (°C/W)	T _A = +25°C, NO AIR FLOW POWER RATING (W)	T _A = +85°C, NO AIR FLOW POWER RATING (W)
Plastic 14-Pin HTSSOP (PWP)	2.07 ⁽⁴⁾	1.6	1.0

For more information on the PWP package, refer to TI Technical Brief (SLMA002A).

Product Folder Link(s): TPS54283 TPS54286

TI device packages are modeled and tested for thermal performance using printed circuit board designs outlined in JEDEC standards JESD 51-3 and JESD 51-7.

For application information, see the *Power Derating* section.

 $T_{J-A} = +40^{\circ}C/W$

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ELECTRICAL CHARACTERISTICS

-40°C $\leq T_J \leq +125$ °C, $V_{PVDD1} = V_{PVDD2} = 12$ V, unless otherwise noted.

INDUT OUT	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	PLY (PVDD)						
V _{PVDD1}	Input voltage range	-		4.5		28	V
V _{PVDD2}	Shutdown		V		70	150	μА
IDD _{SDN}			V _{ENT} = V _{EN2} = V _{PVDD2}		1.8	3.0	μА
IDD _Q	Quiescent, non-switching		V _{FB} = 0.9V, Outputs off SW node unloaded; Measured as BP sink		1.0	3.0	mA
IDD _{SW}	Quiescent, while-switching		current		5		
V_{UVLO}	Minimum turn-on voltage		PVDD2 only	3.8	4.1	4.4	V
V _{UVLO(hys)}	Hysteresis				400		mV
t _{START} (1) (2)	Time from startup to softstart begin		$C_{BP} = 10 \mu F$, $\overline{EN1}$ and $\overline{EN2}$ go low simultaneously		2		ms
ENABLE (E	<u>N</u>)	·	-			ı	
V _{EN1}							
V _{EN2}	Enable threshold			0.9	1.2	1.5	V
	Hysteresis				50		mV
l _{EN1}	Enable pull-up current		V _{EN1} = V _{EN2} = 0 V		6	12	μΑ
I _{EN2}	Enable pull-up current		VENT - VEN2 - U V			12	μΛ
t _{EN} ⁽¹⁾	Time from enable to soft-start begin		Other EN pin = GND		10		μs
BP REGULA	ATOR (BP)						
BP	Regulator voltage		8 V < P _{VDD2} < 28 V	5	5.25	5.6	V
BP_LDO	Dropout voltage		P _{VDD2} = 4.5 V; switching, no external load on BP		400		mV
I _{BP} ⁽¹⁾	Regulator external load					2	
I _{BPS}	Regulator short circuit		4.5 V < P _{VDD2} < 28 V	10	20	30	mA
OSCILLATO	DR .						
	TP	S54283		255	310	375	
f _{SW}	Switching frequency TP	S54286		510	630	750	kHz
t _{DEAD} ⁽¹⁾	Clock dead time				140		ns
	PLIFIER (EA) and VOLTAGE REFERENCE (REF)		-				
V _{FB1}			0°C < T _J < +85°C	788	800	812	
V _{FB2}	Feedback input voltage	-	-40°C < T _J < +125°C	786		812	mV
I _{FB1}			-				
I _{FB2}	Feedback input bias current				3	50	nA
g _M 1 ⁽¹⁾							
g _M 2 ⁽¹⁾	Transconductance				30		μS
SOFT STAR	RT (SS)						
T _{SS1}							
T _{SS2}	 Soft start time 			1.5	2.1	2.7	ms
	RENT PROTECTION						
I _{CL1}	Current limit channel 1			2.4	3.0	3.6	
			$V_{ILIM2} = V_{BP}$	1.15	1.50	1.75	
I _{CL2}	Current limit channel 2	•	V _{ILIM2} = (floating)	2.4	3.0	3.6	Α
			V _{ILIM2} = GND	1.15	1.50	1.75	
V _{UV1}	Low-level output threshold to declare a fault		Measured at feedback pin.		670		mV
V_{UV2}	Store super an obtained to decide a radii				5.0		
T _{HICCUP} ⁽¹⁾	Hiccup timeout				10		ms
t _{ON1(oc)} ⁽¹⁾	Minimum overcurrent pulse width				90	150	ns
t _{ON2(oc)} ⁽¹⁾	wiiminum overcunem pulse wiutii				30	150	110

⁽¹⁾ Ensured by design. Not production tested.

When both outputs are started simultaneously, a 20-mA current source charges the BP capacitor. Faster times are possible with a lower BP capacitor value. More information can be found in the *Input UVLO and Startup* section.

Datasheet of TPS54286PWPR - IC REG BUCK ADJ 2A DL 14HTSSOP

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TPS54283, TPS54286



SLUS749C-JULY 2007-REVISED OCTOBER 2007

ELECTRICAL CHARACTERISTICS (continued)

-40°C \leq T_J \leq +125°C, V_{PVDD1} = V_{PVDD2} = 12 V, unless otherwise noted.

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT	
BOOTSTRA	.P							
R _{BOOT1}	Bootstrap switch resistance	- Bootstrap switch resistance			18		Ω	
R _{BOOT2}	TAGE (Channel 1 and Channel 2)		I _{EXT} = 50 mA					
D (3)	(2)		T _J = +25°C, V _{PVDD2} = 8 V		100		0	
R _{DS(on)} (3)	MOSFET on resistance plus bond wire resist	tance	-40°C < T _J < +125°C, V _{PVDD2} = 8 V		100	180	mΩ	
t _{ON(min)} (3)	Minimum controllable pulse width		I _{SWx} peak current > 1 A ⁽⁴⁾		100	200	ns	
D _{MIN}	Minimum Duty Cycle		V _{FB} = 0.9 V			0	%	
6	Massingum Duty Cyala	TPS54283	f _{SW} = 300 kHz	90	95		%	
D_{MAX}	Maximum Duty Cycle TPS54286		f _{SW} = 600 kHz	85	90		%	
I _{SW}	Switching node leakage current (sourcing)	Outputs OFF		2	12	μΑ		
THERMAL	SHUTDOWN							
T _{SD} ⁽³⁾	Shutdown temperature			148				
T _{SD(hys)} ⁽³⁾	Hysteresis				20		°C	

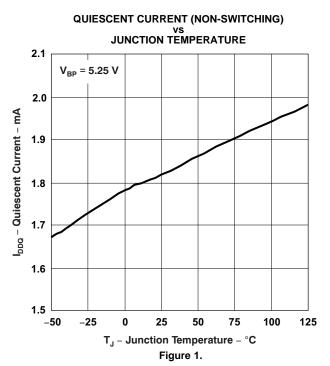
⁽³⁾ Ensured by design. Not production tested.

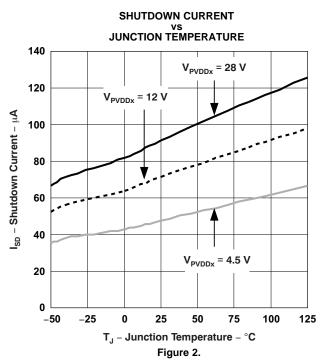
⁽⁴⁾ See Figure 14 for characteristics for I_{SWx} peak current < 1 A.

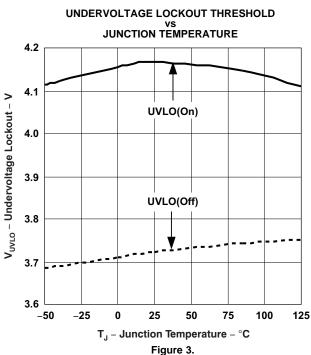


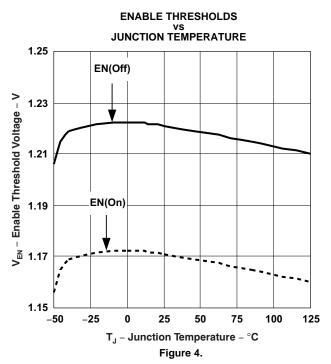


TYPICAL CHARACTERISTICS





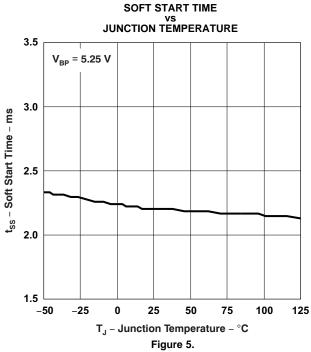


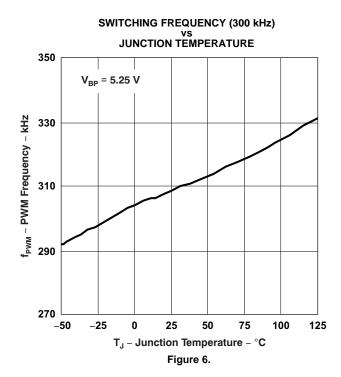


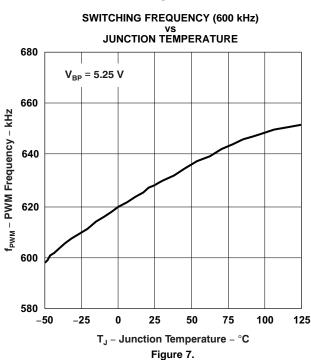
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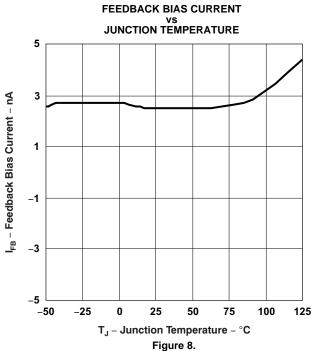
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TYPICAL CHARACTERISTICS (continued)



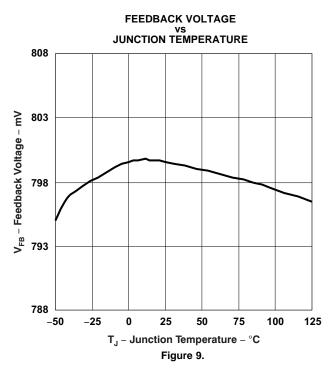






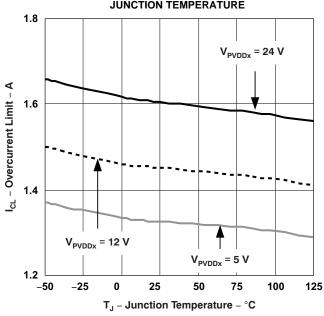


TYPICAL CHARACTERISTICS (continued)



OVERCURRENT LIMIT (CH1, CH2 HIGH LEVEL) vs JUNCTION TEMPERATURE 3.4 $V_{PVDDx} = 24 V$ 3.2 I_{CL} - Overcurrent Limit - A 3.0 2.8 V_{PVDDx} = 12 V 2.6 75 -50 -25 0 25 50 100 125 T_J – Junction Temperature – $^{\circ}$ C

OVERCURRENT LIMIT (CH2 LOW LEVEL) vs JUNCTION TEMPERATURE



SWITCHING NODE LEAKAGE CURRENT vs JUNCTION TEMPERATURE

Figure 10.

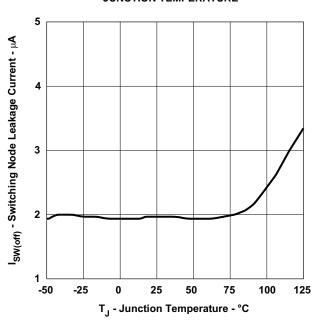


Figure 11.

Figure 12.



TYPICAL CHARACTERISTICS (continued)

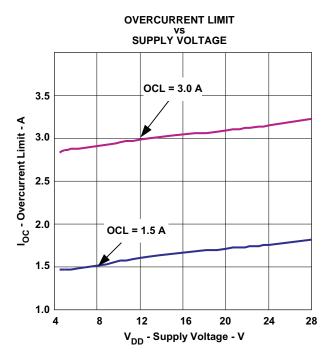


Figure 13.

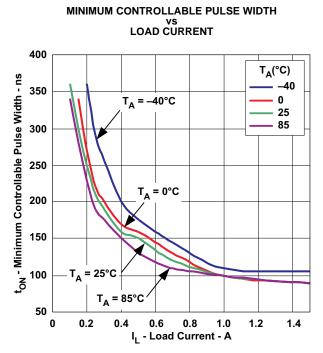


Figure 14.



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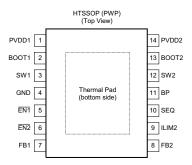




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DEVICE INFORMATION

PIN CONNECTIONS



TERMINAL FUNCTIONS

TERM	MINAL I/O		DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
BOOT1	2	I	Input supply to the high side gate driver for Output 1. Connect a 22-nF to 82-nF capacitor from this pin to SW1. This capacitor is charged from the BP pin voltage through an internal switch. The switch is turned ON during the OFF time of the converter. To slow down the turn ON of the internal FET, a small resistor (1 Ω to 3 Ω) may be placed in series with the bootstrap capacitor.
BOOT2	13	1	Input supply to the high side gate driver for Output 2. Connect a 22-nF to 82-nF capacitor from this pin to SW2. This capacitor is charged from the BP pin voltage through an internal switch. The switch is turned ON during the OFF time of the converter. To slow down the turn ON of the internal FET, a small resistor (1 Ω to 3 Ω) may be placed in series with the bootstrap capacitor.
BP	11	-	Regulated voltage to charge the bootstrap capacitors. Bypass this pin to GND with a low ESR (4.7- μ F to 10- μ F X7R or X5R preferred) ceramic capacitor.
EN1	5	I	Active low enable input for Output 1. If the voltage on this pin is greater than 1.55 V, Output 1 is disabled (high-side switch is OFF). A voltage of less than 0.9 V enables Output 1 and allows soft start of Output 1 to begin. An internal current source drives this pin to PVDD2 if left floating. Connect this pin to GND to force "always ON" operation.
EN2	6	I	Active low enable input for Output 2. If the voltage on this pin is greater than 1.55 V, Output 2 is disabled (high-side switch is OFF). A voltage of less than 0.9 V enables Output 2 and allows soft start of Output 2 to begin. An internal current source drives this pin to PVDD2 if left floating. Connect this pin to GND to force "always ON" operation.
FB1	7	I	Voltage feedback pin for Output 1. The internal transconductance error amplifier adjusts the PWM for Output 1 to regulate the voltage at this pin to the internal 0.8-V reference. A series resistor divider from Output 1 to ground, with the center connection tied to this pin, determines the value of the regulated output voltage. Compensation for the feedback loop is provided internally to the device. See <i>Feedback Loop and Inductor-Capacitor (L-C) Filter</i> section for further information.
FB2	8	I	Voltage feedback pin for Output 2. The internal transconductance error amplifier adjusts the PWM for Output 2 to regulate the voltage at this pin to the internal 0.8-V reference. A series resistor divider from Output 2 to ground, with the center connection tied to this pin, determines the value of the regulated Output voltage. Compensation for the feedback loop is provided internally to the device. See <i>Feedback Loop and Inductor-Capacitor (L-C) Filter</i> section for further information.
GND	4	-	Ground pin for the device. Connect directly to Thermal Pad.
ILIM2	9	I	Current limit adjust pin for Output 2 only. This function is intended to allow a user with asymmetrical load currents (Output 1 load current much greater than Output 2 load current) to optimize component scaling of the lower current output while maintaining proper component derating in a overcurrent fault condition. The discrete levels are available as shown in Table 2. Note: An internal 2-resistor divider (150-k Ω each) connects BP to ILIM2 and to GND.
PVDD1	1	I	Power input to the Output 1 high side MOSFET only. This pin should be locally bypassed to GND with a low ESR ceramic capacitor of $10-\mu F$ or greater.
PVDD2	14	I	The PVDD2 pin provides power to the device control circuitry, provides the pull-up for the EN1 and EN2 pins and provides power to the Output 2 high-side MOSFET. This pin should be locally bypassed to GND with a low ESR ceramic capacitor of 10-μF or greater. The UVLO function monitors PVDD2 and enables the device when PVDD2 is greater than 4.1 V.

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TERMINAL FUNCTIONS (continued)

TERMIN	AL	1/0	DESCRIPTION		
NAME	NO.	1/0			
			This pin configures the output startup mode. If the SEQ pin is connected to BP, then when Output 2 is enabled, Output 1 is allowed to start after Output 2 has reached regulation; that is, sequential startup where Output 1 is slave to Output 2. If $\overline{\text{EN2}}$ is allowed to go high after the outputs have been operating, then both outputs are disabled immediately, and the output voltages decay according to the load that is present. For this sequence configuration, tie $\overline{\text{EN1}}$ to ground.		
SEQ 10 I		I	If the SEQ pin is connected to GND, then when Output 1 is enabled, Output 2 is allowed to start after Output 1 has reached regulation; that is, sequential startup where Output 2 is slave to Output 1. If EN1 is allowed to go high after the outputs have been operating, then both outputs are disabled immediately, and the output voltages decay according to the load that is present. For this sequence configuration, tie EN2 to ground.		
			If left floating, Output 1 and Output 2 start ratio-metrically when both outputs are enabled at the same time. They soft start at a rate determined by their final output voltage and enter regulation at the same time. If the $\overline{\text{EN1}}$ and $\overline{\text{EN2}}$ pins are allowed to operate independently, then the two outputs also operate independently. NOTE: An internal two resistor (150-k Ω each) divider connects BP to SEQ and to GND. See Table 1 Sequencing States.		
SW1	3	0	Source (switching) output for Output 1 PWM. A snubber is recommended to reduce ringing on this node. See SW Node Ringing for further information.		
SW2	12	0	Source (switching) output for Output 2 PWM. A snubber is recommended to reduce ringing on this node. See SW Node Ringing for further information.		
Thermal Pad	-	-	This pad must be tied externally to a ground plane and the GND pin.		

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Product Folder Link(s): TPS54283 TPS54286

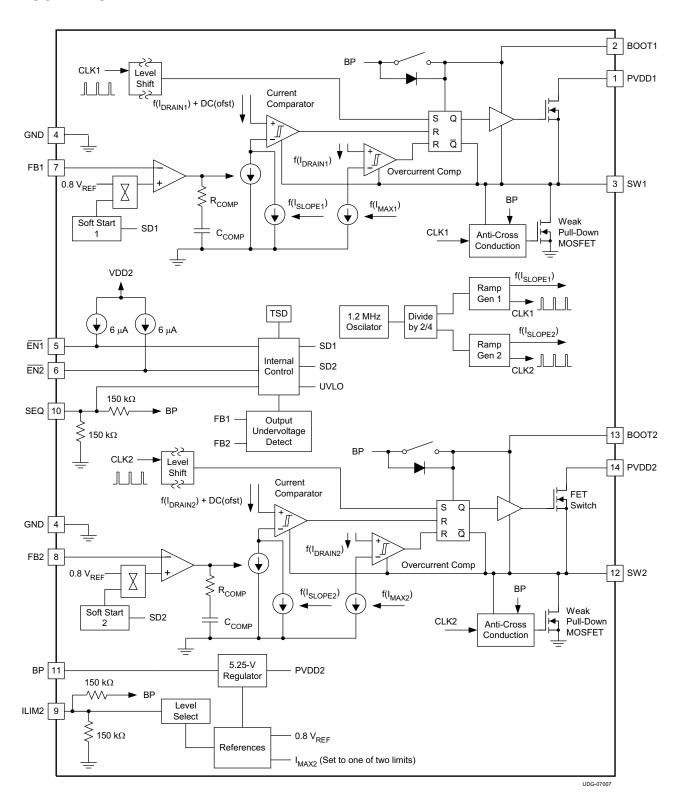
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BLOCK DIAGRAM





APPLICATION INFORMATION

FUNCTIONAL DESCRIPTION

The TPS54283 and TPS54286 are dual output non-synchronous converters. Each PWM channel contains an internally-compensated error amplifier, current mode pulse width modulator (PWM), switch MOSFET, enable, and fault protection circuitry. Common to the two channels are the internal voltage regulator, voltage reference, clock oscillator, and output voltage sequencing functions.

DESIGN HINT

The TPS5428x contains internal slope compensation and loop compensation components; therefore, the external L-C filter must be selected appropriately so that the resulting control loop meets criteria for stability. This approach differs from an externally-compensated controller, where the L-C filter is generally selected first, and the compensation network is found afterwards. (See Feedback Loop and L-C Filter Selection section.)

NOTE:

Unless otherwise noted, the term TPS5428x applies to both the TPS54283 and TPS54286. Also, unless otherwise noted, a label with a lowercase x appended implies the term applies to both outputs of the two modulator channels. For example, the term ENx implies both EN1 and EN2. Unless otherwise noted, all parametric values given are typical. Refer to the *Electrical Characteristics* for minimum and maximum values. Calculations should be performed with tolerance values taken into consideration.

Voltage Reference

The bandgap cell common to both outputs, trimmed to 800 mV.

Oscillator

The oscillator frequency is internally fixed at two times the SWx node switching frequency. The two outputs are internally configured to operate on alternating switch cycles (that is, 180° out of phase).

Input Undervoltage Lockout (UVLO) and Startup

When the voltage at the PVDD2 pin is less than 4.1 V, a portion of the internal bias circuitry is operational, and all other functions are held OFF. All of the internal MOSFETs are also held OFF. When the PVDD2 voltage rises above the UVLO turn-on threshold, the state of the enable pins determines the remainder of the internal startup sequence. If either output is enabled (ENx pulled low), the BP regulator turns on, charging the BP capacitor with a 20 mA current. When the BP pin is greater than 4 V, PWM is enabled and soft start begins, depending on the SEQ mode of operation and the EN1 and EN2 settings.

Note that the internal regulator and control circuitry are powered from PVDD2. The voltage on PVDD1 may be higher or lower than PVDD2. (See the *Dual Supply Operation* section.)

Enable and Timed Turn On of the Outputs

Each output has a dedicated (active low) enable pin. If left floating, an internal current source pulls the pin to PVDD2. By grounding, or by pulling the ENx pin to below approximately 1.2 V with an external circuit, the associated output is enabled and soft start is initiated.

If both enable pins are left in the high state, the device operates in a shutdown mode, where the BP regulator is shut down and minimal functions are active. The total standby current from both PVDD pins is approximately 70 μA at 12-V input supply.

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An R-C connected to an $\overline{\text{ENx}}$ pin may be used to delay the turn-on of the associated output after power is applied to PVDDx (see Figure 15). After power is applied to PVDD2, the voltage on the $\overline{\text{ENx}}$ pin slowly decays towards ground. Once the voltage decays to approximately 1.2 V, then the output is enabled and the startup sequence begins. If it is desired to enable the outputs of the device immediately upon the application of power to PVDD2, then omit these two components and tie the $\overline{\text{ENx}}$ pin to GND directly.

If an R-C circuit is used to delay the turn-on of the output, the resistor value must be much less than 1.2 V / $6\mu A$ or 200 k Ω . A suggested value is 51 k Ω . This resistor value allows the \overline{ENx} voltage to decay below the 1.2-V threshold while the $6-\mu A$ bias current flows.

The capacitor value required to delay the startup time (after the application of PVDD2) is shown in Equation 1.

$$C = \frac{t_{DELAY}}{R \times \ell n \left(\frac{V_{IN} - 2 \times I_{ENx} \times R}{V_{TH} - I_{ENx} \times R} \right)} farads \tag{1}$$

where:

- R and C are the timing components
- V_{TH} is the 1.2-V enable threshold voltage
- I_{FMx} is the 6μA enable pin biasing current

Other enable pin functionality is dictated by the state of the SEQ pin. (See the *Output Voltage Sequencing* section.)

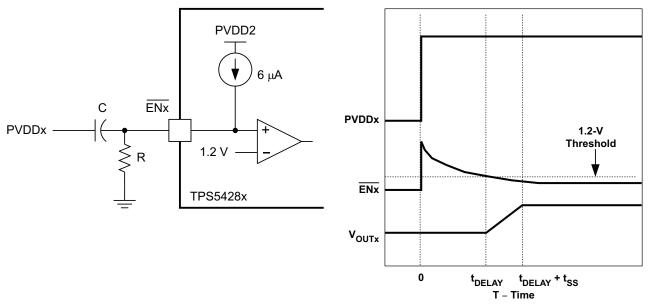


Figure 15. Startup Delay Schematic

Figure 16. Startup Delay with R-C on Enable

DESIGN HINT

If delayed output voltage startup is not necessary, simply connect $\overline{\text{EN1}}$ and $\overline{\text{EN2}}$ to GND. This configuration allows the outputs to start immediately on valid application of PVDD2.

If $\overline{\text{ENx}}$ is allowed to go *high* after the Outputx has been in regulation, the upper MOSFET shuts off, and the output decays at a rate determined by the output capacitor and the load. The internal pulldown MOSFET remains in the OFF state. (See the *Bootstrap for N-Channel MOSFET* section.)

Output Voltage Sequencing

The TPS5428x allows single-pin programming of output voltage startup sequencing. During power-on, the state of the SEQ pin is detected. Based on whether the pin is tied to BP, to GND, or left floating, the outputs behave as described in Table 1.

Table 1. Sequence States

SEQ PIN STATE	MODE	EN1	EN2	
		Ignored by the device when V _{EN2} < enable threshold voltage		
BP	Sequential, Output 2 then Output 1	Tie EN1 to < enable threshold voltage for BP to be active when V _{EN2} > enable threshold voltage	Active	
		Tie $\overline{\text{EN1}}$ to > enable threshold voltage for low quiescent current (BP inactive) when $V_{\overline{\text{EN2}}}$ > enable threshold voltage		
			Ignored by the device when V _{EN1} < enable threshold voltage	
GND	Sequential, Output 1 then Output 2	Active	Tie EN2 to < enable threshold voltage for BP to be active when V _{ENT} > enable threshold voltage	
			Tie EN2 to > enable threshold voltage for low quiescent current (BP inactive) when V _{EN1} > enable threshold voltage	
(floating)	Independent or Ratiometric, Output 1 and Output 2	Active. EN1 and EN2 must be tied together for Ratiometric startup.	Active. EN1 and EN2 must be tied together for Ratiometric startup.	

If the SEQ pin is connected to BP, then when Output 2 is enabled, Output 1 is allowed to start approximately $\frac{400}{\mu}$ s after Output 2 has reached regulation; that is, sequential startup where Output 1 is slave to Output 2. If $\frac{E}{N}$ is allowed to go high after the outputs have been operating, then both outputs are disabled immediately, and the output voltages decay according to the load that is present.

If the SEQ pin is connected to GND, then when Output 1 is enabled, Output 2 is allowed to start approximately $\frac{400}{100}$ μ s after Output 1 has reached regulation; that is, sequential startup where Output 2 is slave to Output 1. If $\overline{\text{EN1}}$ is allowed to go high after the outputs have been operating, then both outputs are disabled immediately, and the output voltages decay according to the load that is present.

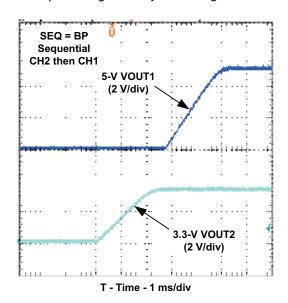


Figure 17. SEQ Pin Tled to BP

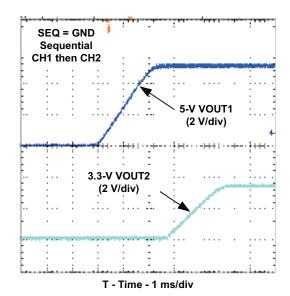


Figure 18. SEQ Pin Tied to GND

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TPS54283, TPS54286



SLUS749C-JULY 2007-REVISED OCTOBER 2007

DESIGN HINT

An R-C network connected to the $\overline{\text{ENx}}$ pin may be used in addition to the SEQ pin in sequential mode to delay the startup of the first output voltage. This approach may be necessary in systems with a large number of output voltages and elaborate voltage sequencing requirements. See *Enable and Timed Turn On of the Outputs*.

If the SEQ pin is left floating, Output 1 and Output 2 each start ratiometrically when both outputs are enabled at the same time. Output 1 and Output 2 soft start at a rate that is determined by the respective final output voltages and enter regulation at the same time. If the $\overline{\text{EN1}}$ and $\overline{\text{EN2}}$ pins are allowed to operate independently, then the two outputs also operate independently.

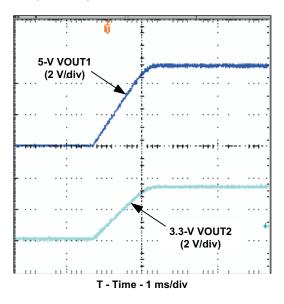


Figure 19. SEQ Pin Floating

Soft Start

Each output has a dedicated soft start circuit. The soft start voltage is an internal digital reference ramp to one of two noninverting inputs of the error amplifier. The other input is the (internal) precision 0.8-V reference. The total ramp time for the FB voltage to charge from 0 V to 0.8 V is about 2.1 ms. During a soft start interval, the TPS5428x output slowly increases the voltage to the noninverting input of the error amplifier. In this way, the output voltage ramps up slowly until the voltage on the noninverting input to the error amplifier reaches the internal 0.8 V reference voltage. At that time, the voltage at the noninverting input to the error amplifier remains at the reference voltage.

NOTE:

To avoid a disturbance in the output voltage during the stepping of the digital soft start, a minimum output capacitance of 50 μF is recommended. Also see Feedback Loop and Inductor-Capacitor (L-C) Filter Selection Once the filter and compensation components have been established, laboratory measurements of the physical design should be performed to confirm converter stability.

During the soft start interval, pulse-by-pulse current limiting is in effect. If an overcurrent pulse is detected, six PWM pulses are skipped to allow the inductor current to decay before another PWM pulse is applied. (See the *Output Overload Protection* section.) There is no pulse skipping if a current limit pulse is not detected.

DESIGN HINT

If the rate of rise of the input voltage (PVDDx) is such that the input voltage is too low

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to support the desired regulation voltage by the time Soft Start has completed, then the output UV circuit may trip and cause a *hiccup* in the output voltage. In this case, use a timed delay startup from the $\overline{\text{ENx}}$ pin to delay the startup of the output until the PVDDx voltage has the capability of supporting the desired regulation voltage. See *Operating Near Maximum Duty Cycle* and *Maximum Output Capacitance* for related information.

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Output Voltage Regulation

Each output has a dedicated feedback loop comprised of a voltage setting divider, an error amplifier, a pulse width modulator, and a switching MOSFET. The regulation output voltage is determined by a resistor divider connecting the output node, the FBx pin, and GND (see Figure 20). Assuming the value of the upper voltage setting divider is known, the value of the lower divider resistor for a desired output voltage is calculated by Equation 2.

$$R2 = R1 \times \left(\frac{V_{REF}}{V_{OUT} - V_{REF}} \right)$$
 (2)

where

• V_{REF} is the internal 0.8-V reference voltage

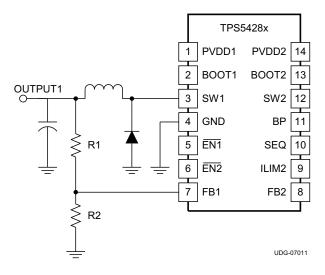


Figure 20. Feedback Network for Channel 1

DESIGN HINT

There is a leakage current of up to 12 μA out of the SW pin when a single output of the TPS5428x is disabled. Keeping the series impedance of R1 + R2 less than 50 k Ω prevents the output from floating above the referece voltage while the controller output is in the OFF state.

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Feedback Loop and Inductor-Capacitor (L-C) Filter Selection

In the feedback signal path, the output voltage setting divider is followed by an internal g_M -type error amplifier with a typical transconductance of 30 μ S. An internal series connected R-C circuit from the g_M amplifier output to ground serves as the compensation network for the converter. The signal from the error amplifier output is then buffered and combined with a slope compensation signal before it is mirrored to be referenced to the SW node. Here, it is compared with the current feedback signal to create a pulse-width-modulated (PWM) signal-fed to drive the upper MOSFET switch. A simplified equivalent circuit of the signal control path is depicted in Figure 21.

NOTE:

Noise coupling from the SWx node to internal circuitry of BOOTx may impact narrow pulse width operation, especially at load currents less than 1 A. See SW Node Ringing for further information on reducing noise on the SWx node.

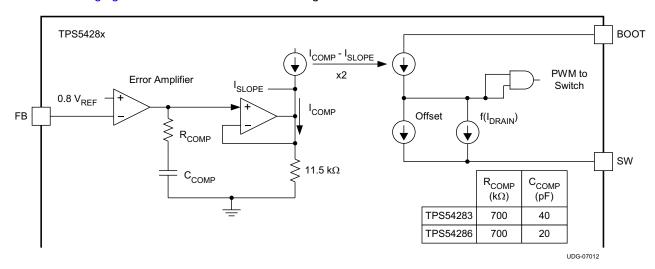


Figure 21. Feedback Loop Equivalent Circuit

A more conventional small signal equivalent block diagram is shown in Figure 22. Here, the full closed loop signal path is shown. Because the TPS5428x contains internal slope compensation and loop compensation components, the external L-C filter must be selected appropriately so that the resulting control loop meets criteria for stability. This approach differs from an externally-compensated controller, where the L-C filter is generally selected first, and the compensation network is found afterwards. To find the appropriate L and C filter combination, the Output-to-Vc signal path plots (see the next section) of gain and phase are used along with other design criterial to aid in finding the combinations that best results in a stable feedback loop.

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270

225

180

135

90

45

0

-90

1 M

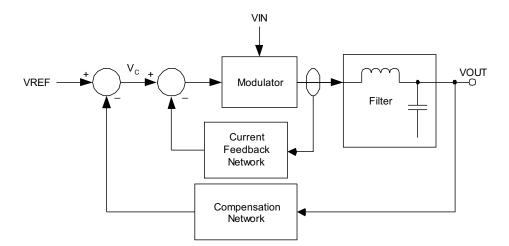


Figure 22. Small Signal Equivalent Block Diagram

Inductor-Capacitor (L-C) Selection

The following figures plot the TPS5428x Output-to-Vc gain and phase versus frequency for various duty cycles (10%, 30%, 50%, 70%, 90%) at three (200 mA, 400 mA, 600 mA) peak-to-peak ripple current levels. The loop response curve selected to compensate the loop is based on the duty cycle of the application and the ripple current in the inductor. Once the curve has been selected and the inductor value has been calculated, the output capacitor is found by calculating the L-C resonant frequency required to compensate the feedback loop. A brief example follows the curves.

Note that the internal error amplifier compensation is optimized for output capacitors with an ESR zero frequency between 20kHz and 60kHz. See the following sections for further details.

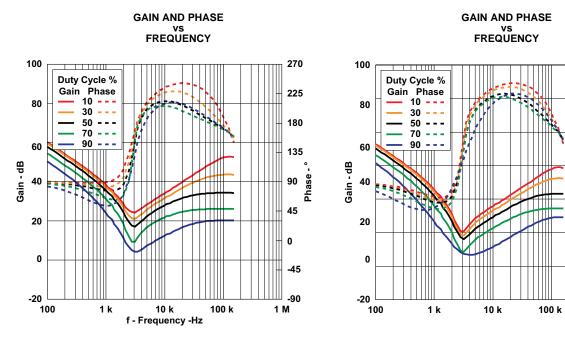


Figure 23. TPS54283 at 200-mAp-p Ripple Current

Figure 24. TPS54283 at 400-mAp-p Ripple Current

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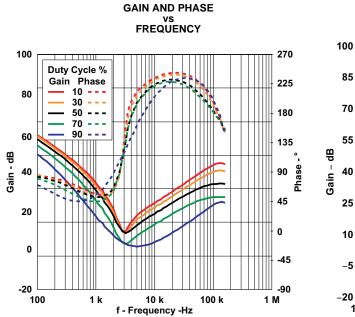


Figure 25. TPS54283 at 600-mAp-p Ripple Current

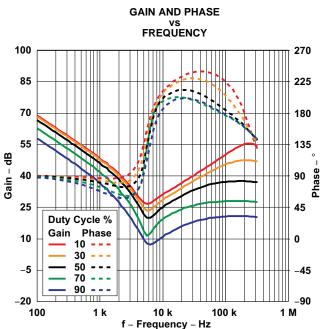


Figure 26. TPS54286 at 200-mAp-p Ripple Current

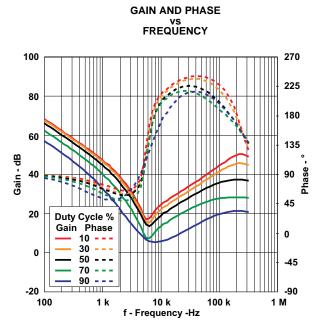


Figure 27. TPS54286 at 400-mAp-p Ripple Current

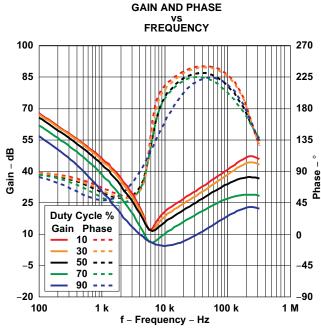


Figure 28. TPS54286 at 600-mAp-p Ripple Current

Maximum Output Capacitance

With internal pulse-by-pulse current limiting and a fixed soft start time, there is a maximum output capacitance which may be used before startup problems begin to occur. If the output capacitance is large enough so that the device enters a current limit protection mode during startup, then there is a possibility that the output will never reach regulation. Instead, the TPS5428x will simply shut down and attempt a restart as if the output were short circuited to ground. The maximum output capacitance (including bypass capacitance distributed at the load) is given by Equation 3:

$$C_{OUTmax} = \frac{t_{SS}}{V_{REF}} \left[I_{CLx} - V_{REF} (1 + \frac{R1}{R2}) (1 - \frac{V_{REF} (1 + \frac{R1}{R2}) \times T_{S}}{2 \times V_{IN} \times L} + \frac{1}{R_{LOAD}}) \right]$$
(3)

Minimum Output Capacitance

Ensure the value of capacitance selected for closed loop stability is compatible with the requirements of Soft Start.

Modifying The Feedback Loop

Within the limits of the internal compensation, there is flexibility in the selection of the inductor and output capacitor values. A smaller inductor increases ripple current, and raises the resonant frequency, thereby increasing the required value of output capacitance. A smaller capacitor could also be used, increasing the resonant frequency, and increasing the overall loop bandwidth—perhaps at the expense of adequate phase margin.

The internal compensation of the TPS54x8x is designed for capacitors with an ESR zero frequency between 20kHz and 60kHz. It is possible, with additional feedback compensation components, to use capacitors with higher or lower ESR zero frequencies. For either case, the components C1 and R3 (ref. Figure 29) are added to re-compensate the feedback loop for stability. In this configuration a low frequency pole is followed by a higher frequency zero. The placement of this pole-zero pair is dependent on the type of output capacitor used, and the desired closed loop frequency response.

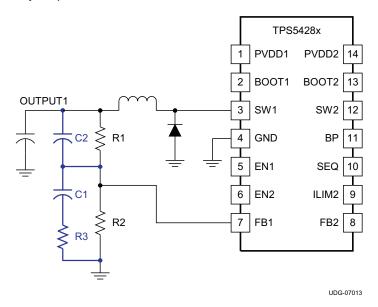


Figure 29. Optional Loop Compensation Components

NOTE:

Once the filter and compensation components have been established, laboratory measurements of the physical design should be performed to confirm converter stability.

Using High-ESR Output Capacitors

If a high ESR capacitor is used in the output filter, a zero appears in the loop response that could lead to instability. To compensate, a small R-C series connected network is placed in parallel with the lower voltage setting divider resistor (Ref Figure 29). The values of the components are determined such that a pole is placed at the same frequency as the ESR zero and a new zero is placed at a frequency location conducive to good loop stability.

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The value of the resistor is calculated using a ratio of impedances to match the ratio of ESR zero frequency to the desired zero frequency.

$$R3 = \frac{R2}{\left(\left(\frac{f_{ZERO(desired)}}{f_{ESR(zero)}}\right) - 1\right)}$$
(4)

where

- $f_{\rm ESR(zero)}$ is the ESR zero frequency of the output capacitor
- f_{ZERO(desired)} is the desired frequency of the zero added to the feedback. This frequency should be placed between 20 kHz and 60 kHz to ensure good loop stability.

The value of the capacitor is calculated in Equation 5.

$$C1 = \frac{1}{2\pi \times R_{EQ} \times f_{ESR(zero)}}$$
(5)

where:

R_{EQ} is an equivalent impedance created by the parallel combination of the voltage setting divider resistors (R1 and R2) in series with R3.

$$R_{EQ} = R3 + \frac{1}{\left(\left(\frac{1}{R1}\right) + \left(\frac{1}{R2}\right)\right)}$$
(6)

Using All Ceramic Output Capacitors

With low ESR ceramic capacitors, there may not be enough phase margin at the crossover frequency. In this case, (Ref Figure 29) resistor R3 is set equal to 1/2 R2. This will lower the gain by 6dB, reduce the crossover frequency, and improve phase margin.

The value of C1 is found by determining the frequency to place the low frequency pole. The minimum frequency to place the pole is 1 kHz. Any lower, and the time constant will be too slow and interfere with the internal soft start. (Ref. Soft Start) The upper bound for the pole frequency is determined by the operating frequency of the converter. It is 3 kHz for the TPS54x83, and 6 kHz for the TPS54x86. C1 is then found from Equation 7. Keep component tolerances in mind when selecting the desired pole frequency.

$$C1 = \frac{1}{2\pi \times R_{EQ} \times f_{POLE(desired)}}$$
(7)

where:

- f_{POLE(desired)} is the desired pole frequency between 1 kHz and 3 kHz (TPS54x83) or 1 kHz and 6 kHz (TPS54x86).
- R_{EQ} is an equivalent impedance created by the parallel combination of the voltage setting divider resistors (R1 and R2) in series with R3.

$$R_{EQ} = R3 + \frac{1}{\left(\left(\frac{1}{R1}\right) + \left(\frac{1}{R2}\right)\right)}$$
(8)

If it is necessary to increase phase margin, place a capacitor in parallel with the upper voltage setting divider resistor (Ref. C2 in Equation 9).

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$$C2 = \frac{1}{2\pi \times f_{C} \times R1} \times \sqrt{1 + \frac{R1}{\left(\frac{(R2 \times R3)}{(R2 + R3)}\right)}}$$

(9)

where

• f_C is the unity gain crossover frequency (approximately 50 kHz for most designs following these guidelines)

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SLUS749C-JULY 2007-REVISED OCTOBER 2007

Example: TPS54286 Buck Converter Operating at 12-V Input, 3.3-V Output and 400-mAp-p Ripple Current

First, the steady state duty cycle is calculated. Assuming the rectifier diode has a voltage drop of 0.5 V, the duty cycle is approximated using Equation 10.

$$\delta = \frac{V_{\text{OUT}} + V_{\text{DIODE}}}{V_{\text{IN}} + V_{\text{DIODE}}} = \frac{3.3 + 0.5}{12 + 0.5} = 30\%$$
(10)

The filter inductor is then calculated; see Equation 11.

$$L = \frac{V_{IN} - V_{OUT}}{\Delta I_L} \times \delta \times T_S = \frac{12 - 3.3}{0.4} \times 0.3 \times \frac{1}{600000} = 10.9 \,\mu\text{H} \tag{11}$$

A custom-designed inductor may be used for the application, or a standard value close to the calculated value may be used. For this example, a standard $10-\mu H$ inductor is used. Using Figure 27, find the 30% duty cycle curve. The 30% duty cycle curve has a down slope from low frequency and rises at approximately 6 kHz. This curve is the resonant frequency that must be compensated. Any frequency wthin an octave of the peak may be used in calculating the capacitor value. In this example, 6 kHz is used.

$$C = \frac{1}{L \times (2 \times \pi \times f_{RES})^2} = \frac{1}{10 \times 10^{-6} \times (2 \times 3.14 \times 6000)^2} = 70 \,\mu\text{F}$$
(12)

A $68-\mu F$ capacitor may be used as a bulk capacitor, with $10-\mu F$ of ceramic bypass capacitance in parallel. To ensure the ESR zero does not significantly impact the loop response, the ESR of the bulk capacitor should be placed a decade above the resonant frequency.

$$R_{ESR} < \frac{1}{2 \times \pi \times 10 \times f_{RES} \times C} = \frac{1}{2 \times 3.14 \times 10 \times 6000 \times 68 \times (10)^{-6}} \approx 40 \text{ m}\Omega$$
(13)

The resulting loop gain and phase are shown in Figure 30. Based on measurement, loop crossover is 45 kHz with a phase margin of 60 degrees.

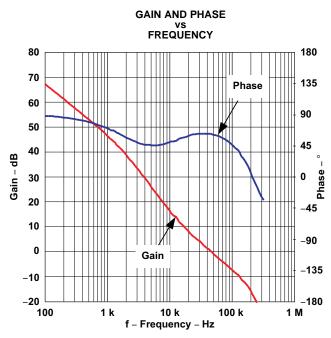


Figure 30. Example Loop Result



Bootstrap for the N-Channel MOSFET

A bootstrap circuit provides a voltage source higher than the input voltage and of sufficient energy to fully enhance the switching MOSFET each switching cycle. The PWM duty cycle is limited to a maximum of 90%, allowing an external bootstrap capacitor to charge through an internal synchronous switch (between BP and BOOTx) during every cycle. When the PWM switch is commanded to turn ON, the energy used to drive the MOSFET gate is derived from the voltage on this capacitor.

To allow the bootstrap capacitor to charge each switching cycle, an internal pulldown MOSFET (from SW to GND) is turned ON for approximately 140 ns at the beginning of each switching cycle. In this way, if, during light load operation, there is insufficient energy for the SW node to drive to ground naturally, this MOSFET forces the SW node toward ground and allow the bootstrap capacitor to charge.

Because this is a charge transfer circuit, care must be taken in selecting the value of the bootstrap capacitor. It must be sized such that the energy stored in the capacitor on a per cycle basis is greater than the gate charge requirement of the MOSFET being used.

DESIGN HINT

For the bootstrap capacitor, use a ceramic capacitor with a value between 22 nF and 82 nF.

DESIGN HINT

For 5-V input applications, connect PVDDx to BP directly. This connection bypasses the internal control circuit regulator and provides maximum voltage to the gate drive circuitry. In this configuration, shutdown mode IDD_{SDN} will be the same as quiescent IDD_{Ω} .

Light Load Operation

There is no special circuitry for pulse skipping at light loads. The normal characteristic of a nonsynchronous converter is to operate in the *discontinuous conduction mode* (DCM) at an average load current less than one-half of the inductor peak-to-peak ripple current. Note that the amplitude of the ripple current is a function of input voltage, output voltage, inductor value, and operating frequency, as shown in Equation 14.

$$I_{DCM} = \frac{1}{2} \times \frac{V_{IN} - V_{OUT}}{L} \times \delta \times T_{S}$$
(14)

During discontinuous comduction mode operation the commanded pulse width may become narrower than the capability of the converter to resolve. To maintain the output voltage within regulation, skipping of switching pulses at light load conditions is a by-product of that mode. This condition may occur if the output capacitor is charged to a value greater than the output regulation voltage, and there is insufficient load to discharge the capacitor. A by-product of pulse skipping is an increase in the peak-to-peak output ripple voltage.

24

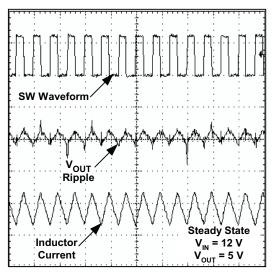
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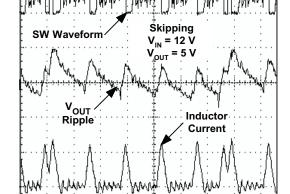


Figure 31. Steady State

Figure 32. Skipping

DESIGN HINT

If additional output capacitance is required to reduce the output voltage ripple during DCM operation, be sure to recheck *Feedback Loop and Inductor-Capacitor (L-C)* Filter Selection and Maximum Output Capacitance sections.

SW Node Ringing

A portion of the control circuitry is referenced to the SW node. To ensure jitter-free operation, it is necessary to decrease the voltage waveform ringing at the SW node to less than 5 volts peak and of a duration of less than 30-ns. In addition to following good printed circuit board (PCB) layout practices, there are a couple of design techniques for reducing ringing and noise.

SW Node Snubber

Voltage ringing observable at the SW node is caused by fast switching edges and parasitic inductance and capacitance. If the ringing results in excessive voltage on the SW node, or erratic operation of the converter, an R-C snubber may be used to dampen the ringing and ensure proper operation over the full load range.

DESIGN HINT

A series-connected R-C snubber (C = between 330 pF and 1 nF, R = 10 Ω) connected from SW to GND reduces the ringing on the SW node.

Bootstrap Resistor

A small resistor in series with the bootstrap capacitor reduces the turn-on time of the internal MOSFET, thereby reducing the rising edge ringing of the SW node.

DESIGN HINT

A resistor with a value between 1Ω and 3Ω may be placed in series with the bootstrap capacitor to reduce ringing on the SW node.

DESIGN HINT

Placeholders for these components should be placed on the initial prototype PCBs in case they are needed.

TPS54283, TPS54286



SLUS749C-JULY 2007-REVISED OCTOBER 2007

Output Overload Protection

In the event of an overcurrent during soft start on either output (such as starting into an output short), pulse-by-pulse current limiting and PWM frequency division (see below) are in effect for that output until the internal soft start timer ends. At the end of the soft start time, a UV condition is declared and a fault is declared. During this fault condition, both PWM outputs are disabled and the small pulldown MOSFETs (from SWx to GND) are turned ON. This process ensures that both outputs discharge to GND in the event that overcurrent is on one output while the other is not loaded. The converter then enters a *hiccup* mode timeout before attempting to restart. "Frequency Division" means if an overcurrent pulse is detected, six clock cycles are skipped before a next PWM pulse is initiated, effectively dividing the operating frequency by six and preventing excessive current build up in the inductor.

In the event of an overcurrent on either output after the output reaches regulation, pulse-by-pulse current limit is in effect for that output. In addition, an output undervoltage (UV) comparator monitors the FBx voltage (that follows the output voltage) to declare a fault if the output drops below 85% of regulation. During this fault condition, both PWM outputs are disabled and the small pulldown MOSFETs (from SWx to GND) are turned ON. This design ensures that both outputs discharge to GND, in the event that overcurrent is on one output while the other is not loaded. The converter then enters a *hiccup* mode timeout before attempting to restart.

The overcurrent threshold for Output 1 is set nominally at 3.0 A. The overcurrent level of Output 2 is determined by the state of the ILIM2 pin. The ILIM setting of Output 2 is not latched in place and may be changed during operation of the converter.

Table 2. Current Limit Threshold Adjustment for Output 2

ILIM2 Connection	OCP Threshold for Output 2	
BP or GND	1.5 A nominal setting	
(floating)	3.0 A nominal setting	

DESIGN HINT

The overcurrent protection threshold refers to the peak current in the internal switch. Be sure to add one-half of the peak inductor ripple current to the dc load current in determining how close the actual operating point is to the OCP threshold.

Operating Near Maximum Duty Cycle

If the TPS5428x operates at maximum duty cycle, and if the input voltage is insufficient to support the output voltage (at full load or during a load current transient), then there is a possibility that the output voltage will fall from regulation and trip the output UV comparator. If this should occur, the TPS5428x protection circuitry will declare a fault and enter a shut down-and-restart cycle.

DESIGN HINT

Ensure that under ALL conditions of line and load regulation, there is sufficient duty cycle to maintain output voltage regulation.

The operating duty cycle under continuous conduction (neglecting losses) is approximated using Equation 15.

$$\delta = \frac{V_{OUT} + V_{DIODE}}{V_{IN} + V_{DIODE}}$$
(15)

where

ullet V_{DIODE} is the voltage drop of the rectifier diode

Dual Supply Operation

It is possible to operate a TPS5428x from two supply voltages. If this application is desired, then the sequencing of the supplies must be such that PVDD2 is above the UVLO voltage before PVDD1 begins to rise. This level requirement ensures that the internal regulator and the control circuitry are in operation before PVDD1 supplies energy to the output. In addition, Output 1 must be held in the disabled state (EN1 high) until there is sufficient voltage on PVDD1 to support Output 1 in regulation. (See the *Operating Near Maximum Duty Cycle* section.)

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TPS54283, TPS54286



SLUS749C-JULY 2007-REVISED OCTOBER 2007

The preferred sequence of events is:

- 1. PVDD2 rises above the input UVLO voltage
- 2. PVDD1 rises with Output 1 disabled until PVDD1 rises above level to support Output 1 regulation. With these two conditions satisfied, there is no restriction on PVDD2 to be greater than, or less than PVDD1.

DESIGN HINT

An R-C delay on EN1 may be used to delay the startup of Output1 for a long enough period of time to ensure that PVDD1 can support Output 1 load.

Cascading Supply Operation

It is possible to source PVDD1 from Output 2 as depicted in Figure 33 and Figure 34. This configuration may be preferred if the input voltage is high, relative to the voltage on Output 1.

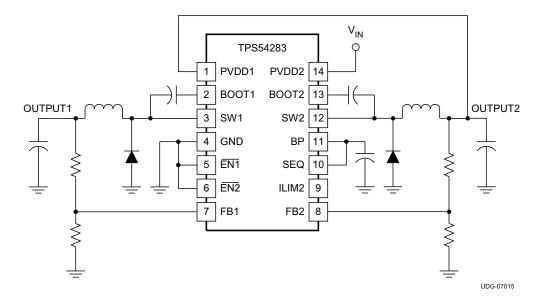


Figure 33. Schematic Showing Cascading PVDD1 from Output 2

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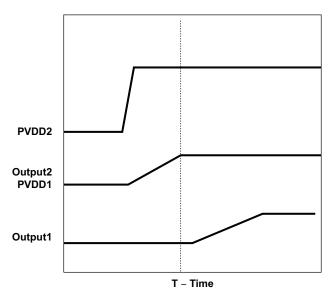


Figure 34. Waveforms Resulting from Cascading PVDD1 from Output 2

In this configuration, the following conditions must be maintained:

- 1. Output 2 must be of a voltage high enough to maintain regulation of Output 1 under all load conditions.
- 2. The sum of the current drawn by Output 2 load plus the current into PVDD1 must be less than the overload protection current level of Output 2.
- 3. The method of output sequencing must be such that the voltage on Output 2 is sufficient to support Output 1 before Output 1 is enabled. This requrement may be accomplished by:
 - a. a delay of the enable function
 - b. selecting sequential sequencing of Output 1 starting after Output 2 is in regulation

Multiphase Operation

The TPS5428x is not designed to operate as a two-phase single-output voltage converter. See http://www.power.ti.com for appropriate device selection.

Bypass and Filtering

As with any integrated circuit, supply bypassing is important for jitter-free operation. To improve the noise immunity of the converter, ceramic bypass capacitors must be placed as close to the package as possible.

- 1. PVDD1 to GND: Use a 10-μF ceramic capacitor
- 2. PVDD2 to GND: Use a 10-μF ceramic capacitor
- 3. BP to GND: Use a 4.7-μF to 10-μF ceramic capacitor

Over-Temperature Protection and Junction Temperature Rise

The over-temperature thermal protection limits the maximum power to be dissipated at a given operating ambient temperature. In other words, at a given device power dissipation, the maximum ambient operating temperature is limited by the maximum allowable junction operating temperature. The device junction temperature is a function of power dissipation, and the thermal impedance from the junction to the ambient. If the internal die temperature should reach the thermal shutdown level, the TPS5428x shuts off both PWMs and remains in this state until the die temperature drops below the hysteresis value, at which time the device restarts.

The first step to determine the device junction temperature is to calculate the power dissipation. The power dissipation is dominated by the two switching MOSFETs and the BP internal regulator. The power dissipated by each MOSFET is composed of conduction losses and output (switching) losses incurred while driving the external rectifier diode. To find the conduction loss, first find the RMS current through the upper switch MOSFET.



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$$I_{RMS(outputx)} = \sqrt{D \times \left(\left(I_{OUTPUTx} \right)^2 + \left(\frac{\left(\Delta I_{OUTPUTx} \right)^2}{12} \right) \right)}$$
(16)

where

- D is the duty cycle
- I_{OUTPUTx} is the DC output current
- ΔI_{OUTPUTx} is the peak ripple current in the inductor for Outputx

Notice the impact of the operating duty cycle on the result.

Multiplying the result by the R_{DS(on)} of the MOSFET gives the conduction loss.

$$P_{D(cond)} = I_{RMS(outputx)}^{2} \times R_{DS(on)}$$
(17)

The switching loss is approximated by:

$$P_{D(SW)} = \left[\frac{\left(V_{IN} \right)^2 \times C_J \times f_S}{2} \right]$$
(18)

where

- where C_J is the parallel capacitance of the rectifier diode and snubber (if any)
- f_S is the switching frequency

The total power dissipation is found by summing the power loss for both MOSFETs plus the loss in the internal regulator.

$$P_{D} = P_{D(cond)output1} + P_{D(SW)output1} + P_{D(cond)output2} + P_{D(SW)output2} + V_{IN} \times Iq$$
(19)

The temperature rise of the device junction depends on the thermal impedance from junction to the mounting pad (See the *Package Dissipation Ratings* table), plus the thermal impedance from the thermal pad to ambient. The thermal impedance from the thermal pad to ambient depends on the PCB layout (PowerPAD interface to the PCB, the exposed pad area) and airflow (if any). See the *PCB Layout Guidelines, Additional References* section.

The operating junction temperature is shown in Equation 20.

$$T_{J} = T_{A} + P_{D} \times \left(\theta_{TH(pkg)} + \theta_{TH(pad-amb)}\right)$$
(20)

Power Derating

The TPS5428x delivers full current at ambient temperatures up to +85°C if the thermal impedance from the thermal pad to ambient is sufficiently low enough to maintain the junction temperature below the thermal shutdown level. At higher ambient temperatures, the device power dissipation must be reduced to maintain the junction temperature at or below the thermal shutdown level. Figure 35 illustrates the power derating for elevated ambient temperature under various airflow conditions. Note that these curves assume that the PowerPAD is properly soldered to the recommended thermal pad. (See the *References* section for further information.)



POWER DISSIPATION vs AMBIENT TEMPERATURE

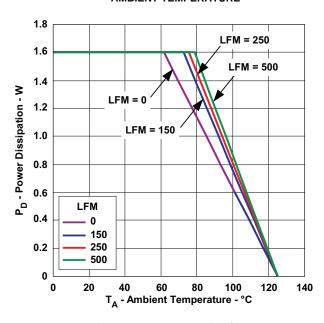


Figure 35. Power Derating Curves



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PowerPAD Package

The PowerPAD package provides low thermal impedance for heat removal from the device. The PowerPAD derives its name and low thermal impedance from the large bonding pad on the bottom of the device. The circuit board must have an area of solder-tinned-copper underneath the package. The dimensions of this area depend on the size of the PowerPAD package. Thermal vias connect this area to internal or external copper planes and should have a drill diameter sufficiently small so that the via hole is effectively plugged when the barrel of the via is plated with copper. This plug is needed to prevent wicking the solder away from the interface between the package body and the solder-tinned area under the device during solder reflow. Drill diameters of 0.33 mm (13 mils) work well when 1-oz. copper is plated at the surface of the board while simultaneously plating the barrel of the via. If the thermal vias are not plugged when the copper plating is performed, then a solder mask material should be used to cap the vias with a diameter equal to the via diameter of 0.1 mm minimum. This capping prevents the solder from being wicked through the thermal vias and potentially creating a solder void under the package. (See the *Additional References* section.)

PCB Layout Guidelines

The layout guidelines presented here are illustrated in the printed circuit board layout example given in Figure 36 and Figure 37.

- The PowerPAD must be connected to a low current (signal) ground plane having a large copper surface area to dissipate heat. Extend the copper surface well beyond the IC package area to maximize thermal transfer of heat away from the IC.
- Connect the GND pin to the PowerPAD through a 10-mil (.010 in, or 0.0254 mm) wide trace.
- Place the ceramic input capacitors close to PVDD1 and PVDD2; connect using short, wide traces.
- Maintain a tight loop of wide traces from SW1 or SW2 through the switch node, inductor, output capacitor and rectifier diode. Avoid using vias in this loop.
- Use a wide ground connection from the input capacitor to the rectifier diode, placed as close to the power
 path as possible. Placement directly under the diode and the switch node is recommended.
- Locate the bootstrap capacitor close to the BOOT pin to minimize the gate drive loop.
- Locate voltage setting resistors and any feedback components over the ground plane and away from the switch node and the rectifier diode to input capacitor ground connection.
- Locate snubber components (if used) close to the rectifier diode with minimal loop area.
- Locate the BP bypass capacitor very close to the IC; a minimal loop area is recommended.
- Locate the output ceramic capacitor close to the inductor output terminal between the inductor and any electrolytic capacitors, if used.

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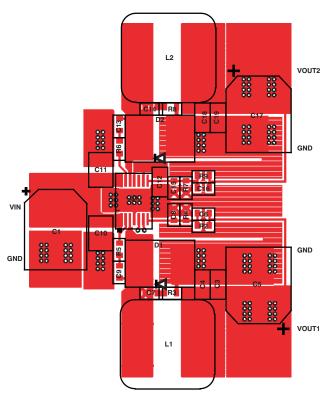


Figure 36. Top Layer Copper Layout and Component Placement

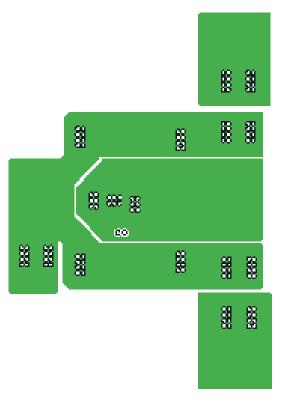


Figure 37. Bottom Layer Copper Layout

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DESIGN EXAMPLES

Example 1: Detailed Design of a 12-V to 5-V and 3.3-V Converter

The following example illustrates a design process and component selection for a 12-V to 5-V and 3.3-V dual non-synchronous buck regulator using the TPS54283 converter. Design Example List of Materials and Table 4, Definition of Symbols is found at the end of this section.

PARAME	TER	NOTES AND CONDITIONS	MIN	NOM	MAX	UNIT
INPUT CH	HARACTERISTICS		,			
V _{IN}	Input voltage		6.9	12.0	13.2	V
I _{IN}	Input current	V _{IN} = nom, I _{OUT} = max		1.6	2.0	Α
	No load input current	V _{IN} = nom, I _{OUT} = 0 A		12	20	mA
OUTPUT	CHARACTERISTICS				•	
V _{OUT1}	Output voltage 1	V _{IN} = nom, I _{OUT} = nom	4.8	5.0	5.2	V
V _{OUT2}	Output voltage 2	V _{IN} = nom, I _{OUT} = nom	3.2	3.3	3.4	
	Line regulation	V _{IN} = min to max			1%	
	Load regulation	I _{OUT} = min to max			1%	
V _{OUT(ripple})	Output voltage ripple	V _{IN} = nom, I _{OUT} = max			50	mV _{PP}
I _{OUT1}	Output current 1	V _{IN} = min to max	0		2.0	
I _{OUT2}	Output current 2	V _{IN} = min to max	0		2.0	
I _{OCP1}	Output overcurrent channel 1	V _{IN} = nom, V _{OUT} = V _{OUT1} = 5%	2.4	3	3.5	Α
I _{OCP2}	Output overcurrent channel 2	V _{IN} = nom, V _{OUT} = V _{OUT2} = 5%	2.4	3	3.5	
	Transient response ΔV _{OUT} from load transient	ΔI _{OUT} = 1 A @ 3 A/μs		200		mV
	Transient response settling time			1		ms
SYSTEM	CHARACTERISTICS					
f_{SW}	Switching frequency		250	310	370	kHz
η	Full load efficiency			85%		
TJ	Operating temperature range		0	25	60	°C

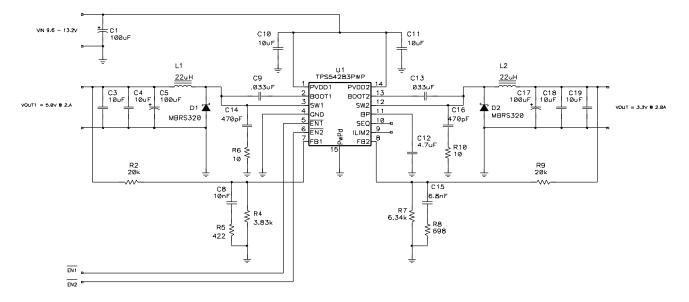


Figure 38. Design Example Schematic

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TEXAS INSTRUMENTS

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Design Procedure

Duty Cycle Estimation

The first step is to estimate the duty cycle of each switching FET.

$$D_{max} \approx \frac{V_{OUT} + V_{FD}}{V_{IN(min)} + V_{FD}}$$
(21)

$$D_{min} \approx \frac{V_{OUT} + V_{FD}}{V_{IN(max)} + V_{FD}}$$
(22)

Using an assumed forward drop of 0.5 V for a schottky rectifier diode, the Channel 1 duty cycle is approximately 40.1% (minimum) to 48.7% (maximum) while the Channel 2 duty cycle is approximately 27.7% (minimum) to 32.2% (maximum).

Inductor Selection

The peak-to-peak ripple is limited to 30% of the maximum output current. This places the peak current far enough from the minimum overcurrent trip level to ensure reliable operation.

For both Channel 1 and Channel 2, the maximum inductor ripple current is 600 mA. The inductor size is estimated in Equation 23.

$$L_{min} \approx \frac{V_{IN(max)} - V_{OUT}}{I_{LRIP(max)}} \times D_{min} \times \frac{1}{f_{SW}}$$
(23)

The inductor values are

- L1 = 18.3 μH
- L2 = 15.3 μH

The next higher standard inductor value of 22 µH is used for both inductors.

The resulting ripple currents are:

$$I_{RIPPLE} \approx \frac{V_{IN(max)} - V_{OUT}}{L} \times D_{min} \times \frac{1}{f_{SW}}$$
(24)

Peak-to-peak ripple currents of 0.498 A and 0.416 A are estimated for Channel 1 and Channel 2 respectively.

The RMS current through an inductor is approximated by Equation 25.

$$I_{L(rms)} = \sqrt{\left(I_{L(avg)}\right)^2 + \frac{1}{12}\left(I_{RIPPLE}\right)^2}$$
(25)

and is approximately 2.0 A for both channels.

The peak inductor current is found using:

$$I_{L(peak)} \approx I_{OUT(max)} + \frac{1}{2}I_{RIPPLE}$$
 (26)

An inductor with a minimum RMS current rating of 2.0 A and minimum saturation current rating of 2.25 A is required. A Coilcraft MSS1278-223ML $22-\mu H$, 6.8-A inductor is selected.

Rectifier Diode Selection

A schottky diode is selected as a rectifier diode for its low forward voltage drop. Allowing 20% over VIN for ringing on the switch node, the required minimum reverse break-down voltage of the rectifier diode is:

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$$V_{(BR)R(min)} \ge 1.2 \times V_{IN} \tag{27}$$

The diode must have reverse breakdown voltage greater than 15.8 V, therefore a 20-V device is used.

The average current in the rectifier diode is estimated by Equation 28.

$$I_{D(avg)} \approx I_{OUT(max)} \times (1 - D)$$
(28)

For this design, 1.2-A (average) and 2.25 A (peak) is estimated for Channel 1 and 1.5-A (average) and 2.21-A (peak) for Channel 2.

An MBRS320, 20-V, 3-A diode in an SMC package is selected for both channels. This diode has a forward voltage drop of 0.4 V at 2 A.

The power dissipation in the diode is estimated by Equation 29.

$$P_{D(max)} \approx V_{FM} \times I_{D(avg)}$$
(29)

For this design, the full load power dissipation is estimated to be 480 mW in D1, and 580 mW in D2.

Output Capacitor Selection

The TPS54283's internal compensation limits the selection of the output capacitors. From Figure 24, the internal compensation has a double zero resonance at about 3 kHz. The output capacitor is selected by Equation 30.

$$C_{OUT} = \frac{1}{4 \times \pi^2 \times (f_{RES})^2 \times L}$$
(30)

Solving for Cout using

- f_{RES} = 3 kHz
- I = 22 µH

The resulting is C_{OUT} = 128 μF . The output ripple voltage of the converter is composed of the ripple voltage across the output capacitor. To find the maximum ESR allowable to meet the output ripple requirements the total ripple is partitioned, and the equation manipulated to find the ESR.

$$ESR_{(max)} = \frac{V_{RIPPLE(tot)} - V_{RIPPLE(cap)}}{I_{RIPPLE}} = \frac{V_{RIPPLE(tot)}}{I_{RIPPLE}} - \frac{D}{f_S \times C_{OUT}}$$
(31)

Based on 128 μ F of capacitance, 300-kHz switching frequency and 50-mV ripple voltage plus rounding up the ripple current to 0.5 A, and the duty cycle to 50%, the capacitive portion of the ripple voltage is 6.5 mV, leaving a maximum allowable ESR of 87 m Ω .

To meet the ripple voltage requirements, a low-cost 100- μ F electrolytic capacitor with 400 m Ω ESR (C5, C17) and two 10- μ F ceramic capacitors (C3 and C4; and C18 and C19) with 2.5-m Ω ESR are selected. From the datasheets for the ceramic capacitors, the parallel combination provides an impedance of 28 m Ω @ 300 kHz for 14 mV of ripple.

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Voltage Setting

The primary feedback divider resistors (R2, R9) from VOUT to FB should be between 10 k Ω and 50 k Ω to maintain a balance between power dissipation and noise sensitivity. For this design, 20 k Ω is selected.

The lower resistors, R4 and R7 are found using the following equations.

$$R4 = \frac{V_{FB} \times R2}{V_{OUT1} - V_{FB}} \tag{32}$$

$$R7 = \frac{V_{FB} \times R9}{V_{OUT2} - V_{FB}}$$
(33)

- $R2 = R9 = 20 \text{ k}\Omega$
- V_{FB} = 0.80 V
- R4= 3.80 k Ω (3.83 k Ω standard value is used)
- R7= 6.40 kΩ (6.34 kΩ standard value is used)

Compensation Capacitors

Checking the ESR zero of the output capacitors:

$$f_{\mathsf{ESR}(\mathsf{zero})} = \frac{1}{2 \times \pi \times \mathsf{C} \times \mathsf{ESR}} \tag{34}$$

- $C = 100 \mu F$
- ESR = 400 mΩ
- ESR_(zero) = 3980 Hz

Since the ESR zero of the main output capacitor is less than 20 kHz, an R-C filter is added in parallel with R4 and R7 to compensate for the electrolytic capacitors' ESR and add a zero about 40 kHz.

$$R5 = \frac{R4}{\left(\left(\frac{f_{ZERO(desired)}}{f_{ESR(zero)}}\right) - 1\right)}$$
(35)

- f_{ESR(zero)} = 4 kHz
- f_{ESR(desired)}= 40 kHz
- $R4 = 3.83 \text{ k}\Omega$
- R5 = 424 Ω (422 Ω selected)
- $R7 = 6.34 \text{ k}\Omega$
- R8 = 702Ω (698 Ω selected)

$$R_{EQ} = R5 + \frac{1}{\left(\left(\frac{1}{R2}\right) + \left(\frac{1}{R4}\right)\right)}$$

(36)

- R2 = R9 = 20 kΩ
- REQ1 = $3.63 \text{ k}\Omega$
- REQ2 = $5.51 \text{ k}\Omega$

$$C8 = \frac{1}{2 \times \pi \times R_{EQ} \times f_{ESR(zero)}}$$

(37)

- C8 = 10.9 nF (10 nF selected)
- C15 = 7.22 nF (6800 pF selected)

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TPS54283, TPS54286



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Input Capacitor Selection

The TPS54283 datasheet recommends a minimum $10-\mu F$ ceramic input capacitor on each PVDD pin. These capacitor must be capable of handling the RMS ripple current of the converter. The RMS current in the input capacitors is estimated by Equation 38.

$$I_{RMS(outputx)} = \sqrt{D \times \left(\left(I_{OUTPUTx} \right)^2 + \left(\frac{\left(\Delta I_{OUTPUTx} \right)^2}{12} \right) \right)}$$
(38)

• $I_{RMS(CIN)} = 0.43 \text{ A}$

One 1210 10- μ F, 25 V, X5R ceramic capacitor with 2-m Ω ESR and a 2-A RMS current rating are selected for each PVDD input. Higher voltage capacitors are selected to minimize capacitance loss at the DC bias voltage to ensure the capacitors maintains sufficient capacitance at the working voltage.

Boot Strap Capacitor

To ensure proper charging of the high-side FET gate and limit the ripple voltage on the boost capacitor, a 33-nF boot strap capacitor is used.

ILIM

Current limit must be set above the peak inductor current $I_{L(peak)}$. Comparing $I_{L(peak)}$ to the available minimum current limits, ILIM is left floating for the highest current limit level.

SEQ

The SEQ pin is left floating, leaving the enable pins to function independently. If the enable pins are tied together, the two supplies start-up ratiometrically. Alternatively, SEQ could be connected to BP or GND to provide sequential start-up.

Power Dissipation

The power dissipation in the TPS54283 is composed of FET conduction losses, switching losses and internal regulator losses. The RMS FET current is found using Equation 39.

$$I_{RMS(Outputx)} = \sqrt{D \times \left(\left(I_{OUTPUT} \right)^2 + \frac{\left(\Delta I_{(Outputx)} \right)^2}{12} \right)}$$
(39)

This results in 1.05-A RMS for Channel 1 and 0.87-A RMS for Channel 2.

Conduction losses are estimated by:

$$P_{CON} = R_{DS(on)} \times \left(Q_{SW(rms)} \right)^{2}$$
(40)

Conduction losses of 198 mW and 136 mW are estimated for Channel 1 and Channel 2 respectively.

The switching losses are estimated in Equation 41.

$$P_{SW} \approx \frac{\left(V_{IN(max)}\right)^{2} \times \left(C_{DJ} + C_{OSS}\right) \times f_{SW}}{2}$$
(41)

From the data sheet of the MBRS320, the junction capacitance is 658 pF. Since this is large compared to the output capacitance of the TPS54x8x the FET capacitance is neglected, leaving switching losses of 17 mW for each channel.

The regulator losses are estimated in Equation 42.

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$$P_{REG} \approx I_{DD} \times V_{IN(max)} + I_{BP} \times \left(V_{IN(max)} - V_{BP}\right)$$
(42)

With no external load on BP (I_{BP}=0) the regulator power dissipation is 66 mW.

Total power dissipation in the device is the sum of conduction and switching for both channels plus regulator losses.

The total power dissipation is P_{DISS} =0.198+0.136+0.017+0.017+.066 = 434 mW.

Design Example Test Results

The following results are from the TPS54283-001 EVM.

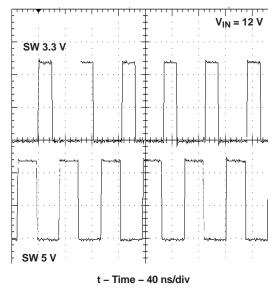


Figure 39. Switching Node Waveforms

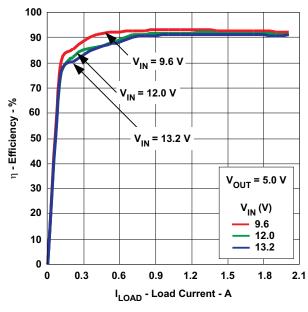


Figure 40. 5.0-V Output Efficiency vs. Load Current

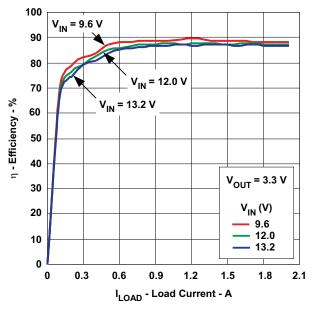


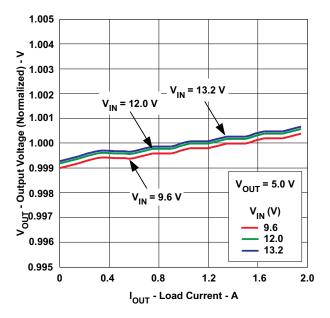
Figure 41. 3.3-V Output Efficiency vs. Load Current

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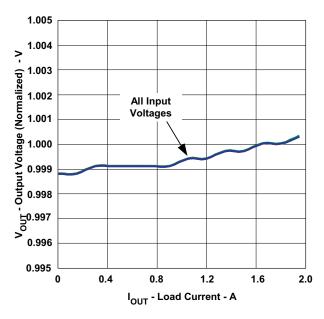


Figure 42. 5.0-V Output Voltage vs. Load Current

Figure 43. 3.3-V Output Voltage vs. Load Current

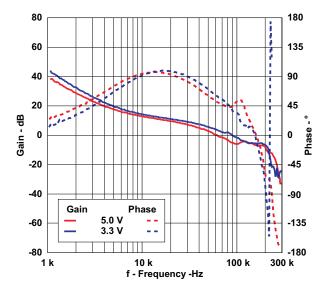


Figure 44. Example 1 Loop Response



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Table 3. Design Example List of Materials

QTY	REFERENCE DESIGNATOR	VALUE	DESCRIPTION	SIZE	PART NUMBER	MANUFACTURER	
1	C1	100 μF	Capacitor, Aluminum, 25V, 20%	E-can	EEEFC1E101P	Panasonic	
2	C10, C11	10 μF	Capacitor, Ceramic, 25V, X5R 20%	1210	C3216X5R1E106M	TDK	
1	C12	4.7 μF	Capacitor, Ceramic, 10V, X5R 20%	0805	Std	Std	
2	C14, C16	470 pF	Capacitor, Ceramic, 25V, X7R, 20%	0603	Std	Std	
1	C15	6.8 nF	Capacitor, Ceramic, 25V, X7R, 20%	0603	Std	Std	
1	C17, C5	100 μF	Capacitor, Aluminum, 10V, 20%, FC Series	F-can	EEEFC1A101P	Panasonic	
4	C3, C4, C18, C19	10 μF	Capacitor, Ceramic, 6.3V, X5R 20%	0805	C2012X5R0J106M	TDK	
1	C8	10 nF	Capacitor, Ceramic, 25V, X7R, 20%	0603	Std	Std	
2	C9, C13	0.033 μF	Capacitor, Ceramic, 25V, X7R, 20%	0603	Std	Std	
2	D1, D2	MBRS320	Diode, Schottky, 3-A, 30-V	SMC	MBRS330T3	On Semi	
2	L1, L2	22 μΗ	Inductor, Power, 6.8A, 0.038 Ω	0.484 x 0.484	MSS1278-153ML	Coilcraft	
2	R2, R9	20 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std	
1	R5	422 Ω	Resistor, Chip, 1/16W, 1%	0603	Std	Std	
2	R6, R10	10 Ω	Resistor, Chip, 1/16W, 5%	0603	Std	Std	
1	R8	698 Ω	Resistor, Chip, 1/16W, 1%	0603	Std	Std	
1	R4	3.83 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std	
1	R7	6.34 kΩ	Resistor, Chip, 1/16W, 1%	0603	Std	Std	
1	U1		TPS54283 DC-DC Switching Converter w/ FET	HTSSOP -14	TPS54283PWP	TI	

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Table 4. Definition of Symbols

C _{DJ}	Average junction capacitance of the rectifier diode from 0V to VIN(max)
C _{OSS}	Average output capacitance of the switching MOSFET from 0V to VIN(max)
C _{OUT}	Output Capacitor
D _(max)	Maximum steady state operating duty cycle
D _(min)	Minimum steady state operating duty cycle
ESR _(max)	Maximum allowable output capacitor ESR
f _{SW}	Switching frequency
I _{BP}	Output Current of BP regulator due to external loads
I _{DD}	Switching quiescent current with no load on BP
I _{D(avg)}	Average diode conduction current
I _{D(peak)}	Peak diode conduction current
I _{IN(avg)}	Average input current
I _{IN(rms)}	Root mean squared (RMS) input current
I _{L(avg)}	Average inductor current
I _{L(rms)}	Root mean squared (RMS) inductor current
I _{L(peak)}	Peak current in inductor
I _{LRIP(max)}	Maximum allowable inductor ripple current
L _(min)	Minimum inductor value to maintain desired ripple current
I _{OUT(max)}	Maximum designed output current
I _{RMS(cin)}	Root mean squared (RMS) current through the input capacitor
I _{RIPPLE}	Inductor peak to peak ripple current
I _{QSW(rms)}	Root mean squared current through the switching MOSFET
P _{CON}	Power loss due to conduction through switching MOSFET
P _{D(max)}	Maximum power dissipation in diode
R _{DS(on)}	Drain to source resistance of the switching MOSFET when "ON"
P _{SW}	Power loss due to switching
P _{REG}	Power loss due to the internal regulator
V_{BP}	Output Voltage of BP regulator
$V_{(BR)R(min)}$	Minimum reverse breakdown voltage rating for rectifier diode
V_{FB}	Regulated feedback voltage
V_{FD}	Forward voltage drop across rectifier diode
V _{IN}	Power stage input voltage
V _{OUT}	Regulated output voltage
V _{RIPPLE(cap)}	Peak to Peak ripple voltage due to ideal capacitor (ESR = 0)
V _{RIPPLE(tot)}	Maximum allowable peak to peak output ripple voltage

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Additional Design Examples

Example 2: 24-V to 12-V and 24-V to 5-V

For a higher input voltage, both a snubber and bootstrap resistors are added to reduce ringing on the switch node and a 30 V schottky diode is selected. A higher resistance feedback network is chosen for the 12 V output to reduce the feedback current.

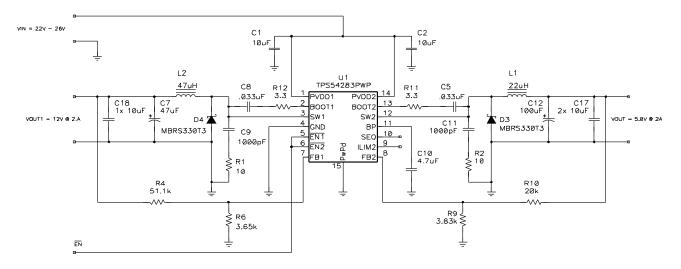


Figure 45. 24-V to 12-V and 24-V to 5-V Using the TPS54283

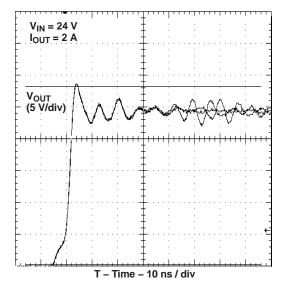


Figure 46. Switch Node Ringing Without Snubber and Boost Resistor

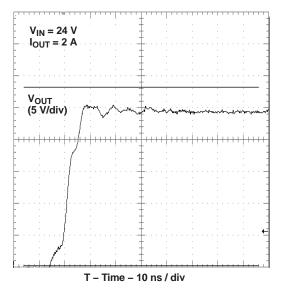


Figure 47. Switch Node Ringeing With Snubber and Boost Resistor



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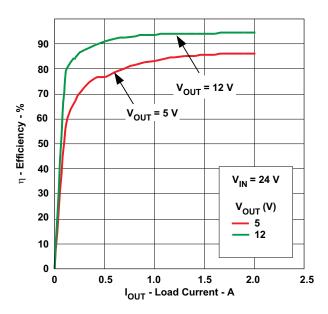


Figure 48. Efficiency vs. Load Current

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Example 3: 5-V to 3.3V and 5-V to 1.2 V

For a low input voltage application, the TPS54286 is selected for reduced size and all ceramic output capacitors are used. $22-\mu F$ input capacitors are selected to reduce input ripple and lead capacitors are placed in the feedback to boost phase margin.

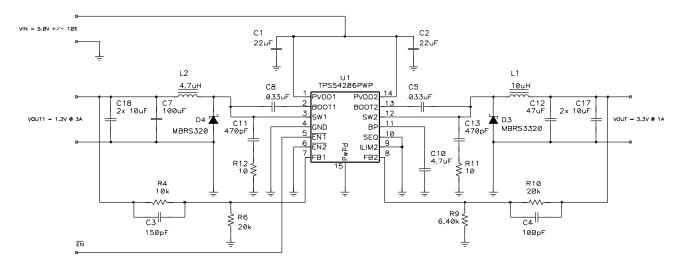
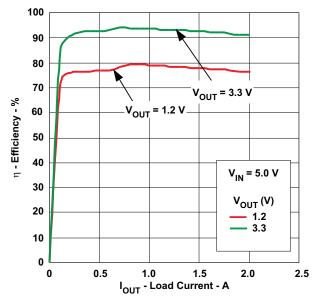
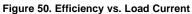


Figure 49. 5-V to 3.3V and 5-V to 1.2 V





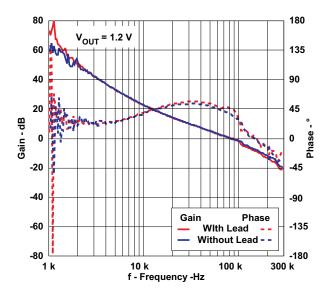


Figure 51. Example 3 Loop Response

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TPS54283, TPS54286

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ADDITIONAL REFERENCES

Related Devices

The following parts have characteristics similar to the TPS54283/6 and may be of interest.

Table 5. Devices Related to the TPS54283 and TPS54286

TI LITERATURE NUMBER	DEVICE	DESCRIPTION
SLUS642	TPS40222	5-V Input, 1.6-A Non-Synchronous Buck Converter
SLUS774	TPS54383 / TPS54386	3-A Dual Non-Synchronous Converter with Integrated High-Side MOSFET

References

These references, design tools and links to additional references, including design software, may be found at http://www.power.ti.com

Table 6. References

TI LITERATURE NUMBER	DESCRIPTION						
SLMA002	PowerPAD Thermally Enhanced Package Application Report						
SLMA004	PowerPAD™ Made Easy						
SLUP206	Under The Hood Of Low Voltage DC/DC Converters. SEM1500 Topic 5, 2002 Seminar Series						
SLVA057	Understanding Buck Power Stages in Switchmode Power Supplies						
SLUP173	Designing Stable Control Loops. SEM 1400, 2001 Seminar Series						

Package Outline and Recommended PCB Footprint

The following pages outline the mechanical dimensions of the 14-Pin PWP package and provide recommendations for PCB layout.

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PACKAGE OPTION ADDENDUM

9-Sep-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS54283PWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54283	Samples
TPS54283PWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54283	Samples
TPS54283PWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54283	Samples
TPS54283PWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54283	Samples
TPS54286PWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54286	Samples
TPS54286PWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54286	Samples
TPS54286PWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54286	Samples
TPS54286PWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	54286	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Ti's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Addendum-Page 1



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PACKAGE OPTION ADDENDUM

www.ti.com 9-Sep-2014

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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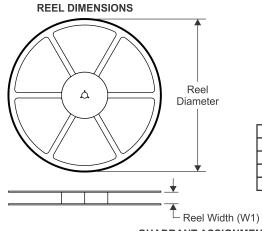
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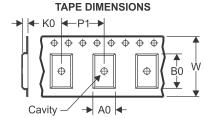


PACKAGE MATERIALS INFORMATION

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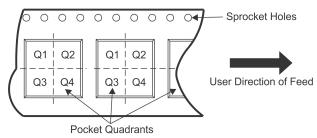
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

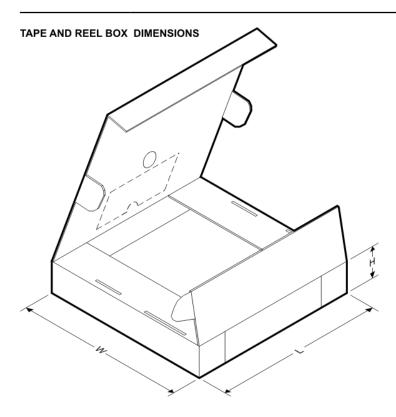
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54283PWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TPS54286PWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

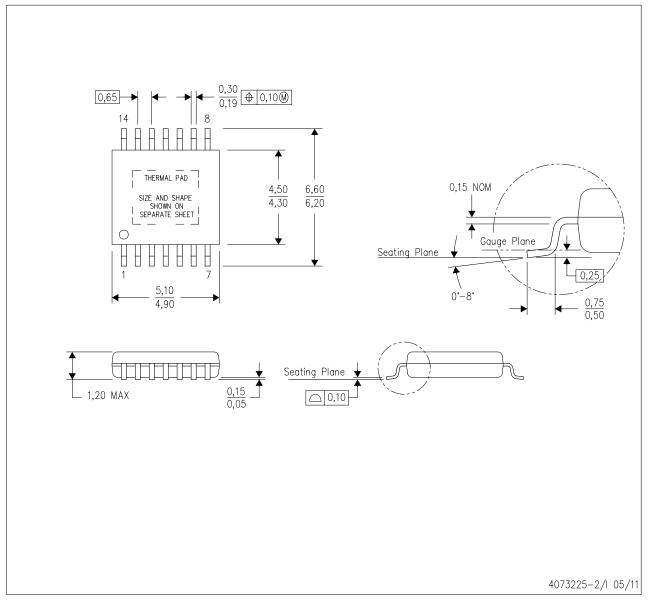
7 till difficilities die fierminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS54283PWPR	HTSSOP	PWP	14	2000	367.0	367.0	38.0
TPS54286PWPR	HTSSOP	PWP	14	2000	367.0	367.0	38.0



MECHANICAL DATA

PWP (R-PDSO-G14)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com www.ti.com>.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- E. Falls within JEDEC MO-153

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THERMAL PAD MECHANICAL DATA

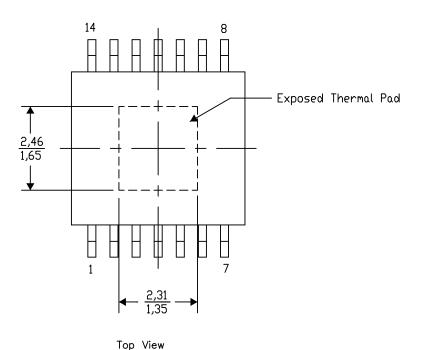
PWP (R-PDSO-G14) PowerPAD[™] SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206332-2/AO 01/16

NOTE: A. All linear dimensions are in millimeters

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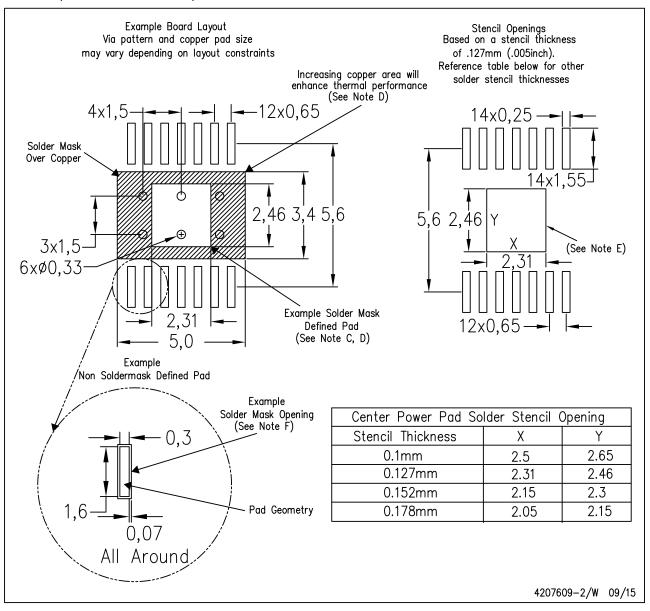




LAND PATTERN DATA

PWP (R-PDSO-G14)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





THERMAL PAD MECHANICAL DATA

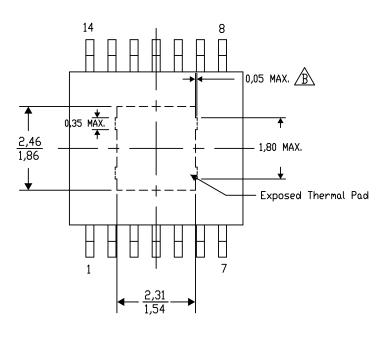
PWP (R—PDSO—G14) PowerPAD[™] SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-44/AO 01/16

NOTE: A. All linear dimensions are in millimeters

A Exposed tie strap features may not be present.

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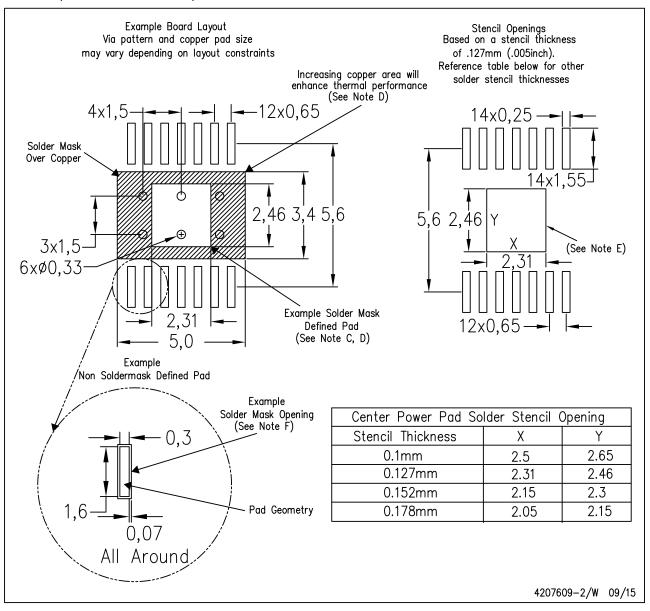




LAND PATTERN DATA

PWP (R-PDSO-G14)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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